RSC Advances



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Cite this: RSC Adv., 2017, 7, 35752

Enhancing perovskite film fluorescence by simultaneous near- and far-field effects of gold nanoparticles

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Received 16th June 2017 Accepted 13th July 2017 DOI: 10.1039/c7ra06744e

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In this work gold nanoparticles (Au NPs) are incorporated into a PEDOT:PSS layer, resulting in \sim 4.0 fold enhanced fluorescence emission of a CH₃NH₃PbBr₃ film. Through experiments and theoretical simulation, we first demonstrated that the enhancement comes from the simultaneous near- and farfield effects of Au NP enhanced perovskite fluorescence.

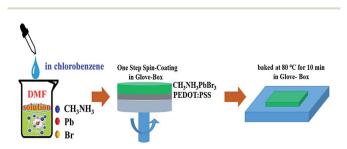
Organic-inorganic hybrid halide perovskites have emerged as a new class of photovoltaic materials with high efficiencies driven by the large absorbance and long-range balanced electron and hole transportation.^{1,2} Recently, perovskites have been making definitive strides as promising light-emitting diodes (LEDs) and for use in tuneable amplified spontaneous emission lasing.³⁻⁶ During the past two years, impressive progress has been made in perovskite LEDs (PeLEDs) and lasing devices; one of the most important tasks is increasing the photoluminescence efficiency of active layer materials,^{7,8} because the electroluminescence (EL) efficiency is theoretically proportional to the photoluminescence (PL) efficiency.9 Driven by this motivation, scientists not only attempted different material structures of the active layer, but also searched for ways of achieving additional photo-physical assistance during device fabrication for further enhancement.10-12

Metallic nanostructures have been widely employed in the organic optoelectronic devices for performance improvement, due to their optical and electrical effect such as metal enhanced fluorescence (MEF),^{13–19} energy transfer,²⁰ electrical effect,^{21,22} and so on.^{23,24} The enhancement utilizing MEF effect usually has a close dependence on the distance between the emitters and the surface of the metallic nanoparticles (NPs). When the fluorophore molecule is brought into the proximity of the metallic NPs based substrate, two maximum enhancements would be observed as a function of the interlayer thickness, which would be originated from near-field (less than 10 nm)¹⁴

and far-field (greater than 60 nm).²⁴⁻²⁷ Recently, Balakrishnan *et al.* reported the enhanced PL intensity of CsPbBr₃ nanocrystals by perovskites–gold (Au) hybrid structure;²⁸ Zhang *et al.* inserted silver nanorods into NPB layer to improve the PeLEDs performance.²⁹ The enhancement reported above arised from near-field effect of metal NPs. Nevertheless, in theoretically with the appropriate devices structure, the near- and far-field effect of Au NPs both could overlap the emitting region of perovskites (usually with thickness of tens to hundreds nanometers). Specifically, the simultaneous utilizing near- and far-field would enhance fluorescence greater than single optical effect of metal NPs. However, as far as we know, there is very few reports focus on the dual-optical effect of metallic NPs enhance perovskites film fluorescence.

In this paper, ~4.0 fold enhanced fluorescence intensity of $CH_3NH_3PbBr_3$ (MAPbBr₃) film was achieved by doping Au NPs into the PEDOT:PSS buffer layer. We demonstrated that the enhancement originated from the simultaneous near- and far-field optical effect of Au NPs *via* experiments and theoretical simulation, which was also the first report that utilizing the dual near- and far-field optical effect in metal enhanced perovskites fluorescence.

The preparation of the mixed MAPbBr₃ perovskites film is summarized in Scheme 1. The PEDOT:PSS was spin-coated onto



Scheme 1 The preparation of the mixed MAPbBr₃ perovskites.

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Paper

the quartz substrate (4500 rpm, 40 s) and baked at 120 °C for 20 min under ambient conditions. The MAPbBr₃ solution was prepared by dissolving CH₃NH₃Br and PbBr₂ (Xi'an Polymer Light Technology Corp, CH₃NH₃Br >99.9%, PbBr₂ >99.9%) with 1.5 : 1 molar ratio in DMF (Alfa-Aesar, anhydrous) solution (the concentration ratio is based on our previous research work¹¹). Then chlorobenzene solution was added dropwise into MAPbBr₃ DMF until saturation, in order to accelerate crystallization of perovskites. The precursor solution was spin-coated onto PEDOT:PSS film in the glove-box (H₂O and O₂ ≤0.1 ppm) at a speed of 4000 rpm for 60 s, and annealed at 80 °C for 10 min.

X-ray diffraction (XRD) pattern displayed in Fig. 1a gave diffraction peaks at 14.90°, 21.08°, 29.98°, 33.62°, 36.92°, 42.94° and 45.68°, which were assigned to the (100), (110), (200), (210), (211), (220) and (300) planes of perovskites structure, respectively. According to the previous report,30 the XRD indicated pure perovskites phase for MAPbBr₃, which suggested a lamellar structure with PbBr₂ 2D-layer parallel to the substrate. The inset of Fig. 1a showed the MAPbBr₃ film (deposited on quartz/PEDOT:PSS substrate) with ~365 nm UVlight irradiation. The cross-section SEM image of the device has also been given in Fig. 1b, the thicknesses of the MAPbBr₃ film was \sim 500 nm under the fabrication method. Top view of SEM images of the MAPbBr₃ film can be seen in Fig. 1c. It exhibited a uniform and dense surface morphology with average grain size of 300-500 nm. Au NPs used here of 20 nmdiameter size (TEM image in inset Fig. 2a) were synthesized according to the classical Frens method,³¹ the typical extinction 520 nm of the Au NPs aqueous solution was shown in Fig. 2a.

The PL spectra (with \sim 365 nm excitation) and absorbance spectra of MAPbBr₃ film were shown in Fig. 2a. It can be seen that the MAPbBr₃ film showed a typical green emission around \sim 534 nm with narrow FWHM of \sim 24 nm.

The maximum fluorescence intensity enhancement showed about ~4.0 fold after doping Au NPs into PEDOT:PSS under the optimized concentration 12 pM in Fig. 2b. With the increased Au NPs concentration, the PL intensity increased (in inset Fig. 2b). The absorbance spectra and time-resolved PL spectra in Fig. 2c and d provided the direct evidence of the increased PL intensity. The absorbance intensity of MAPbBr₃ film improved 45% under 12 pM concentration Au NPs doping, because of the enhanced absorbance probability (get rid of the Au NPs absorbance).32 The time-resolved PL spectra of MAPbBr3 layer on PEDOT: PSS film in Fig. 2d showed the exciton lifetime is 7.28 ns without Au NPs, but surprisingly, decreases to 0.31 ns with Au NPs. Therefore, time-resolved PL measurement provided the direct observation of the enhanced spontaneous emission rate of MAPbBr₃ induced by Au NPs. From the inset in Fig. 2b-d, PL would be decreased until the critical point 12 pM, which maybe due to the nanoparticles aggregation at the high Au NPs density.14,16 High aggregation Au NPs would exposed out of the PEDOT:PSS surface (top view and cross-section of SEM as shown in Fig. 3a-d), then the direct contact between Au NPs and MAPbBr₃ film would seriously quench the fluorescence by nonradiative Fröster energy transfer.14,33

In order to explore the enhancement mechanism, we simulate the near- and far-field model around Au NPs in Fig. 4. The energy matching and distance dependence characters would be the primary difference. For near-field, when the frequency of

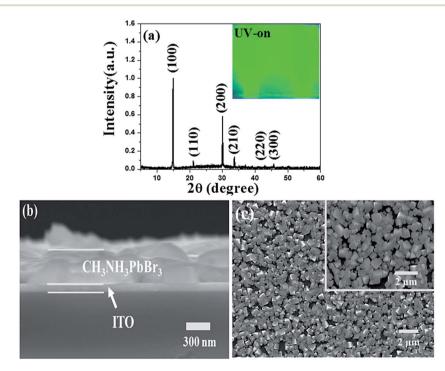


Fig. 1 (a) XRD spectra of green-emitting MAPbBr₃ crystal film, inset: image of MAPbBr₃ film under UV-365 nm excitation, (b) cross-section SEM and (c) SEM image of MAPbBr₃ film.

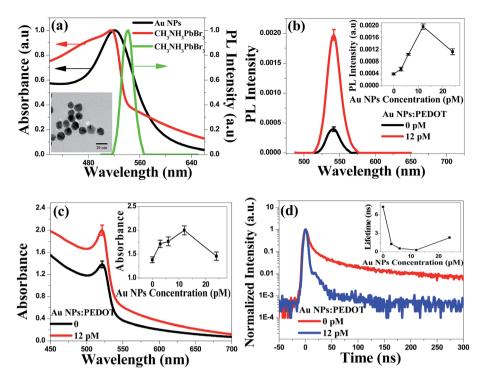


Fig. 2 (a) Photoluminescence spectra of MAPbBr₃ film, absorbance spectra of MAPbBr₃ film and Au NPs aqueous solution respectively, inset: TEM image of Au NPs. (b) Photoluminescence spectra, (c) UV-vis spectra, (d) time-resolved PL spectra in the presence of MAPbBr₃ film on PEDOT:PSS doping into Au NPs. The inset in (b–d) is the photoluminescence, UV-vis and time-resolved PL spectra changing uptrend under different Au NPs doping ratio.

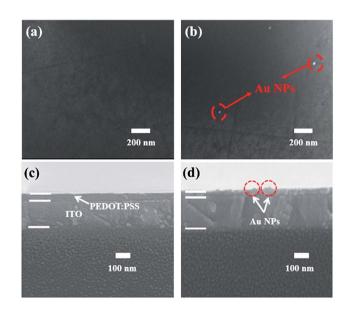


Fig. 3 Top view and cross-section of SEM image of the dispersion of Au NPs in PEDOT:PSS under (a) low, (c) none, (b and d) high concentration doping ratio.

incident light is located in the resonant frequency of metallic NPs, resonance will occur to form the near-field effect around metallic NPs in the range of 5–10 nm. Fig. 4a shows the near electric-field distribution of 20 nm-Au NPs simulated by finite-different time-domain (FDTD). We can see that the electric-

field intensity strongly distribute around the neighbourhood of the NPs, and working distance is in the range of 5–10 nm. The intensity of near-field degraded very quickly as a function of

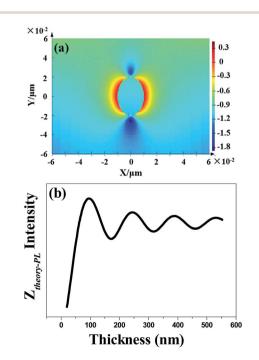


Fig. 4 Theoretical simulation of (a) near-electric field profile, (b) far-field distribution.

distance, which is nearly disappeared when distance larger than 10 nm. The thickness of PEDOT:PSS thin film is the key factors to determine the effective coupling between near-field and emissive layer. Thus, the thickness of PEDOT:PSS buffer layer (less than 30 nm) would be thin enough to put the emitting layer into the scoped of near-field as shown in Scheme 2a.

For far-field, the enhancement ratio for respective wavelength is not related to the intrinsic frequency of metallic NPs as in near-field effect, but depends on fluorophore/metallic NPs distance *d* and refractive index of media *n*. Thus enhancement for different wavelength would be easily achieved by distance *d* optimization. We also established the model of far-field enhancement of Au NPs. Recently we demonstrated utilizing far-field of Au NPs to enhance chromophores emissive in the full-visible spectral range in organic light-emitting diodes.^{14,15,25} The enhancement factor $Z_{\text{theory-PL}}$ of far-field effect is given by

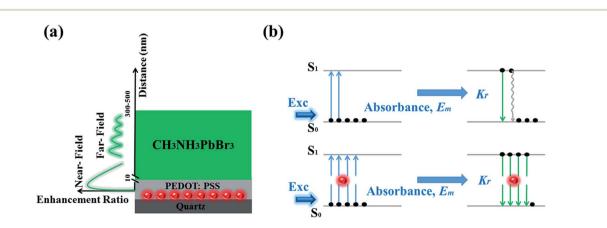
$$Z_{\text{theory-PL}} = q_{\text{d}}/q = \left\{ q + (1-q) \left[1 + \frac{3}{2}qR \right] \right\}$$
$$\times \left(-\frac{\sin(\gamma-\delta)}{\gamma^3} + \frac{\sin(\gamma-\delta)}{\gamma} + \frac{\cos(\gamma-\delta)}{\gamma^2} \right]^{-1}$$

in which q and q_d is quantum yield before and after the introducing of metal NPs, δ is phase shift at the reflection, R is reflectivity, γ is arbitrary value and defined as $\gamma = 4\pi nd/\lambda$, where *n* is refractive index of luminescence material, λ is the emission wavelength. The enhancement factors of quantum yield as a function of distance d are displayed in Fig. 4b (supposing R =1 (total reflect) and $\delta = \pi$ (idea metal mirror)). By increasing of distance, the theoretical PL enhancement Z_{theory-PL} in MAPbBr₃ material presents the trend: at first it would rise with the increased distance and then it would reduce after the maximum value. The far-field enhancement shows multi-enhancement peak in the thickness of emitting layer, combining with the device structure in Scheme 2a. Thus near- and far-field could both overlap the emitting layer. And our previous work demonstrated that 20 nm-size Au NPs doping into PEDOT:PSS shows negligible effect on scattering effect.²⁵ Compare to singleoptical enhancement effect of Au NPs, there are mainly two advantages by simultaneous utilizing near- and far-field of Au NPs: (1) considering the device structure (Scheme 2a), it is easy

to realize dual-optical effect enhancement in perovskites light emitting devices and lasing devices; (2) the fluorescence enhancement ratio by dual-optical effect would be larger than single-optical effect.

To further deeply understand the mechanism of the effective emissive enhancement by doping Au NPs, we proposed that multiple plasmonic enhancing processes induced by dualoptical effect as shown in Scheme 2b. As shown in Scheme 2b, there are two main processes occur when excited: absorbance and radiative velocity. Firstly in the absorption process, the ground state electrons transit from the lowest vibrational level of S₀ to a higher vibrational level of excited state S₁ and soon return to the lowest vibrational level of S1 by non-radiative internal conversion (IC) process. Then the excited electrons transit from the lowest vibrational level of S_1 to S_0 by radiative and non-radiative ways. 20 nm-Au NPs were buried in the PEDOT:PSS film randomly with proper distances to the MAPbBr₃ layer. Through multiple surface plasmonic effects, the absorbance probability of MAPbBr3 can be significantly enhanced, therefore more electrons transit to higher energy level S₁ by electromagnetic field (combining with Fig. 2c). From the lowest vibrational level of S_1 to S_0 , the addition of Au NPs induces faster radiative velocity (combining with Fig. 2d) and leads enhanced emission. Thus, the presence of Au NPs increases the population excited electrons, and enhance the radiative velocity. Based on the multiple enhancements of absorbance and emission during light excitation, the enhancement of fluorescence will be much more effective under near- and far-field together.

In a conclusion, we achieved about ~4.0 fold fluorescence enhancement through doping Au NPs into the PEDOT:PSS. Both the experimental and theoretical results have testified that it mainly attributes to multiple near- and far-field effect of Au NPs. The scope of the near- and far-field of Au NPs could both cover with the MAPbBr₃ film, which means it in favour of fluorescence enhancement most. And it is also the advantage that utilizing Au NPs enhancing the MAPbBr₃ film fluorescence emissive. Our results may offer that Au NPs constitute a feasible and effective rout for achieving high-performance perovskites light-emitting diodes and lasing devices.



Scheme 2 (a) The near- and far-field distribution in devices, (b) diagrams of the procedure of emission without and with Au NPs.

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Acknowledgements

This work was supported by the National Natural Science Foundation of China (Grant No. 11602243, 11504300, 51473052), NSFA of China (Grant No. U1630125), Natural Science Foundation Project of CQ CSTC (Grant No. cstc2015jcyjA50002).

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